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Modern Physics of Ferroelectrics:

Essential Background

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APPENDIX A –

Landau Free-Energy Coefficients

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1 BaTiO₃ 364

2 SrTiO₃ 365

3 PbZr_{1-x}Ti_xO₃ (PZT) 366

4 PbTiO₃ 368

5 LiTaO₃ and LiNbO₃ 368

6 Sr_{0.8}Bi_{2.2}Ta₂O₉ 369

7 SrBi₂Nb₂O₉ 369

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